

N-channel 80 V, 4.2 mOhm MOSFET with enhanced SOA in LFPAK56E

25 June 2021

Preliminary data sheet

1. General description

N-channel enhancement mode MOSFET in a LFPAK56E package qualified to 175 °C. Part of Nexperia's "ASFETs for hotswap" portfolio, the PSMN4R2-80YSE delivers very low R_{DSon} and a very strong linear-mode (SOA) performance in a high-reliability copper-clip LFPAK56E package.

PSMN4R2-80YSE complements the latest "hot-swap" controllers – robust enough to withstand substantial inrush currents during turn-on, low R_{DSon} to minimize I^2R losses delivering optimum efficiency when turned fully ON and an 80% smaller footprint than existing D2PAK types.

2. Features and benefits

- Fully optimized Safe Operating Area (SOA) for superior linear mode operation
- Low R_{DSon} for low I²R conduction losses
- LFPAK56E package for applications that demand the highest performance and reliability in a 30 mm² footprint

3. Applications

- Hot swap
 - Load switch
- Soft start
- E-fuse
- Telecommunication systems based on a 48 V backplane/supply rail

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	-	80	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	-	170	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	-	294	W
Tj	junction temperature		-55	-	175	°C
Static chara	acteristics	· · · ·				
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12	-	3.2	4.2	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; Fig. 13	-	4.6	6.4	mΩ
Dynamic ch	naracteristics	· · ·				
Q _{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 40 V; V _{GS} = 10 V;	3	11	26	nC
Q _{G(tot)}	total gate charge	T _j = 25 °C; <u>Fig. 14; Fig. 15</u>	37	73	110	nC

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Symbol	Parameter	Conditions		Min	Тур	Мах	Unit	
Avalanche r	Avalanche ruggedness							
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$\label{eq:linear} \begin{array}{l} I_D = 57 \; A; \; V_{sup} \leq \; 80 \; V; \; R_{GS} = 50 \; \Omega; \\ V_{GS} = 10 \; V; \; T_{j(init)} = 25 \; ^\circC; \; unclamped; \\ \hline Fig. \; 4 \end{array}$	[1]	-	-	374	mJ	
Source-drai	n diode							
Q _r	recovered charge	$\label{eq:IS} \begin{array}{l} {\sf I}_{\rm S} = 25 \; {\sf A}; \; {\sf dI}_{\rm S} / {\sf dt} = -100 \; {\sf A} / {\sf \mu}{\sf s}; \; {\sf V}_{\rm GS} = 0 \; {\sf V}; \\ {\sf V}_{\rm DS} = 40 \; {\sf V}; \; {\sf T}_{\rm j} = 25 \; {\rm ^{\circ}C}; \; \underline{{\sf Fig. 18}} \end{array}$		-	35	-	nC	

[1] Protected by 100% test

5. Pinning information

Table 2	. Pinning info	rmation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	reen	
2	S	source		
3	S	source		D
4	G	gate		
mb	D	mounting base; connected to drain	LFPAK56E; Power- SO8 (SOT1023)	G the s

6. Ordering information

Table 3. Ordering information

Type number			
	Name	Description	Version
PSMN4R2-80YSE		plastic, single-ended surface-mounted package (LFPAK56); 4 leads; 1.27 mm pitch	SOT1023

7. Marking

Table 4. Marking codes					
Type number	Marking code				
PSMN4R2-80YSE	4E2S80J				

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

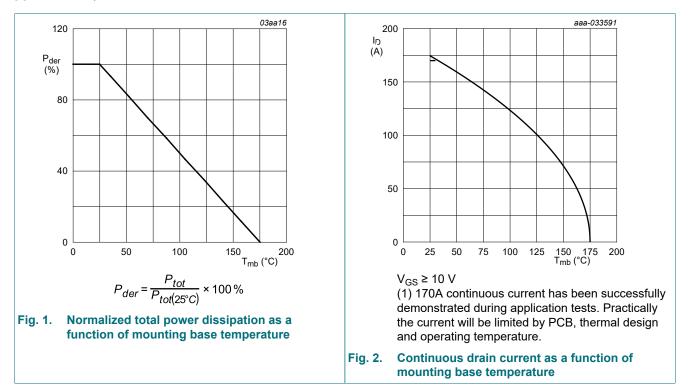
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	80	V
V _{DGR}	drain-gate voltage	25 °C ≤ T _j ≤ 175 °C; R _{GS} = 20 kΩ	-	80	V
V _{GS}	gate-source voltage		-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	294	W

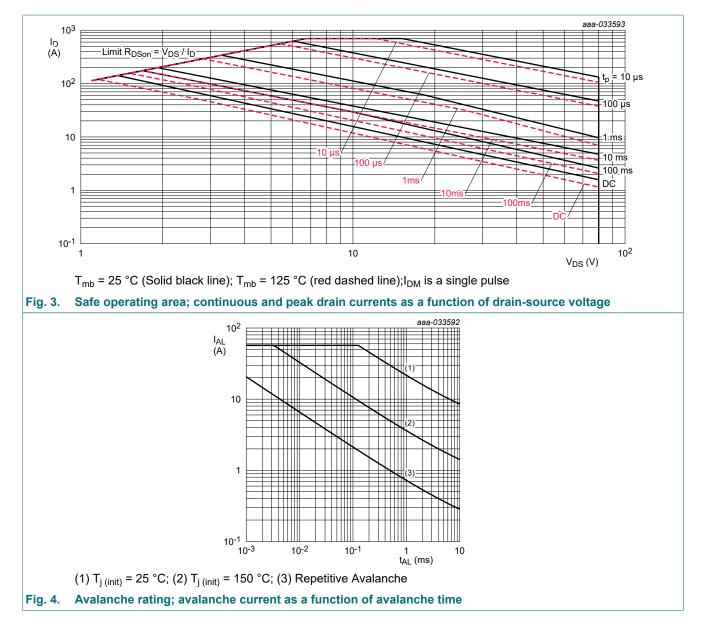
PSMN4R2-80YSE

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Symbol	Parameter	Conditions		Min	Мах	Unit
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	170	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	123	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	698	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drai	n diode					
Is	source current	T _{mb} = 25 °C		-	170	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	698	А
Avalanche r	uggedness	1		I		
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$ \begin{array}{l} I_D = 57 \text{ A}; \ V_{sup} \leq \ 80 \text{ V}; \ R_{GS} = 50 \ \Omega; \\ V_{GS} = 10 \text{ V}; \ T_{j(init)} = 25 \ ^\circ\text{C}; \ unclamped; \\ \hline Fig. \ 4 \end{array} $	[1]	-	374	mJ
I _{AS}	non-repetitive avalanche current		[1]	-	57	A

[1] Protected by 100% test

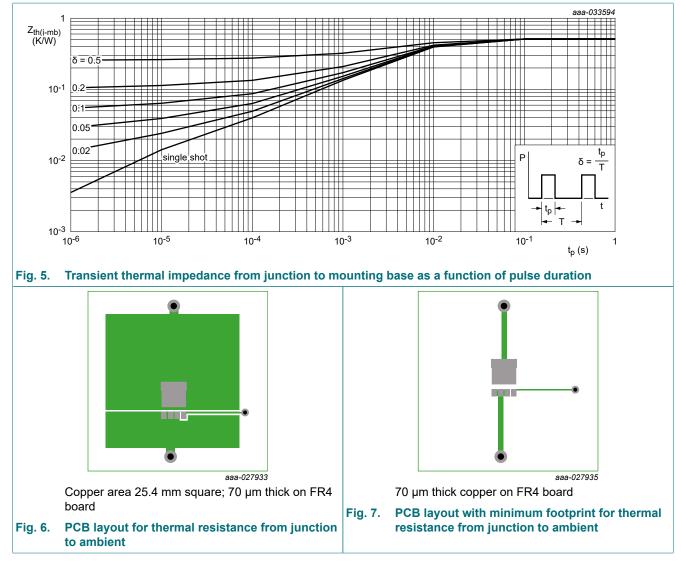




9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	0.45	0.51	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	Fig. 6	-	42	-	K/W
		<u>Fig. 7</u>	-	85	-	K/W

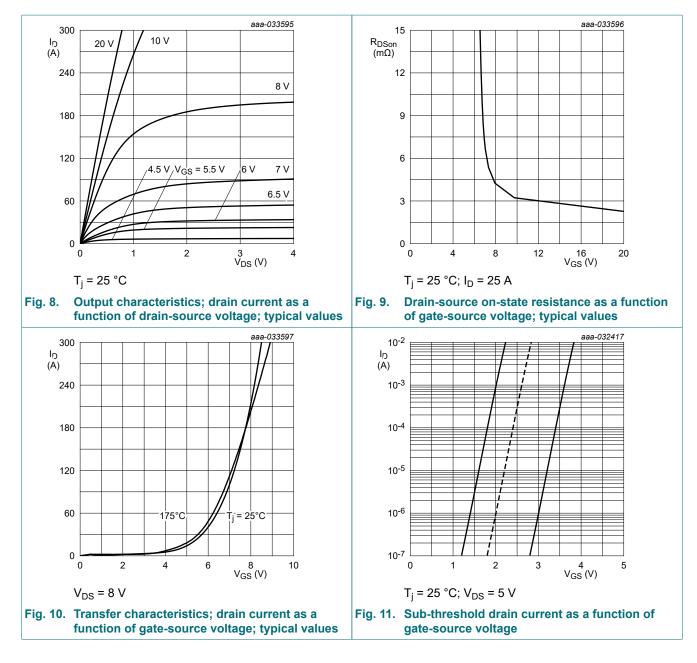


10. Characteristics

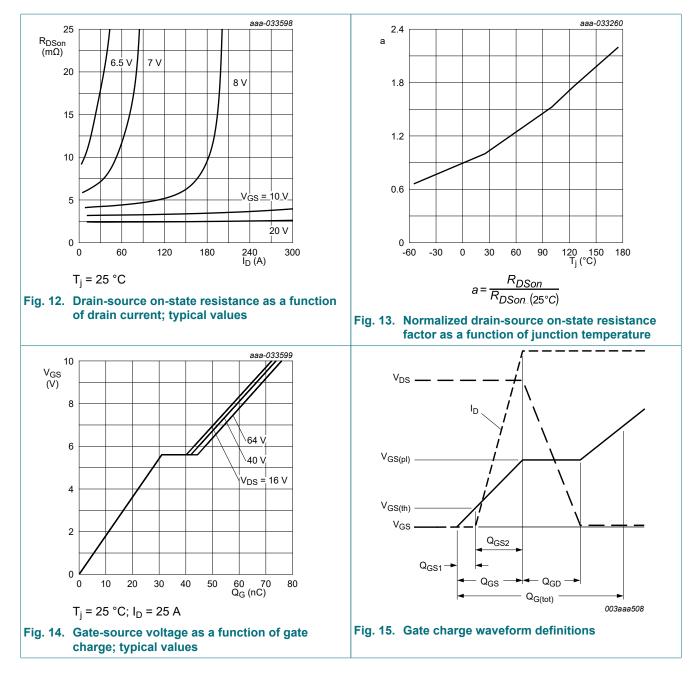
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics	· · ·				
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	80	-	-	V
	breakdown voltage	$I_D = 250 \ \mu A; V_{GS} = 0 \ V; T_j = -55 \ ^{\circ}C$	72	-	-	V
V _{GS(th)}	gate-source threshold	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}; Fig. 11$	2	2.6	3.6	V
	voltage	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C	-	1.6	-	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C	-	3	-	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-6.1	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 80 V; V _{GS} = 0 V; T _j = 25 °C	-	0.02	1	μA
		V _{DS} = 80 V; V _{GS} = 0 V; T _j = 125 °C	-	5.5	100	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _i = 25 °C	-	2	100	nA

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12	-	3.2	4.2	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; <u>Fig. 13</u>	-	4.6	6.4	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; <u>Fig. 13</u>	-	6.3	9.3	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	0.52	1.04	2.08	Ω
Dynamic ch	aracteristics					
Q _{G(tot)}	total gate charge	$I_{D} = 25 \text{ A}; V_{DS} = 40 \text{ V}; V_{GS} = 10 \text{ V}; T_{j} = 25 \text{ °C}; Fig. 14; Fig. 15$	37	73	110	nC
		$ I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}; T_j = 25 \ ^{\circ}\text{C} $	-	40	-	nC
Q _{GS}	gate-source charge	$I_D = 25 \text{ A}; V_{DS} = 40 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}; \overline{\text{Fig. 14}}; \overline{\text{Fig. 15}}$	18	31	43	nC
Q _{GS(th)}	pre-threshold gate- source charge		-	16.2	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	14.8	-	nC
Q _{GD}	gate-drain charge		3	11	26	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 40 V; T _j = 25 °C; Fig. 14; Fig. 15	-	5.6	-	V
C _{iss}	input capacitance	V _{DS} = 40 V; V _{GS} = 0 V; f = 0.5 MHz;	3429	5714	8000	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 16</u>	893	1488	2381	pF
C _{rss}	reverse transfer capacitance	-	5	55	164	pF
t _{d(on)}	turn-on delay time	V_{DS} = 40 V; R _L = 1.6 Ω; V _{GS} = 10 V;	-	23	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	25	-	ns
t _{d(off)}	turn-off delay time	1 [-	32	-	ns
t _f	fall time	7	-	24	-	ns
Source-drai	in diode					
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 17</u>	-	0.81	1	V
t _{rr}	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$	-	38	-	ns
Qr	recovered charge	V _{DS} = 40 V; T _j = 25 °C; <u>Fig. 18</u>	-	35	-	nC

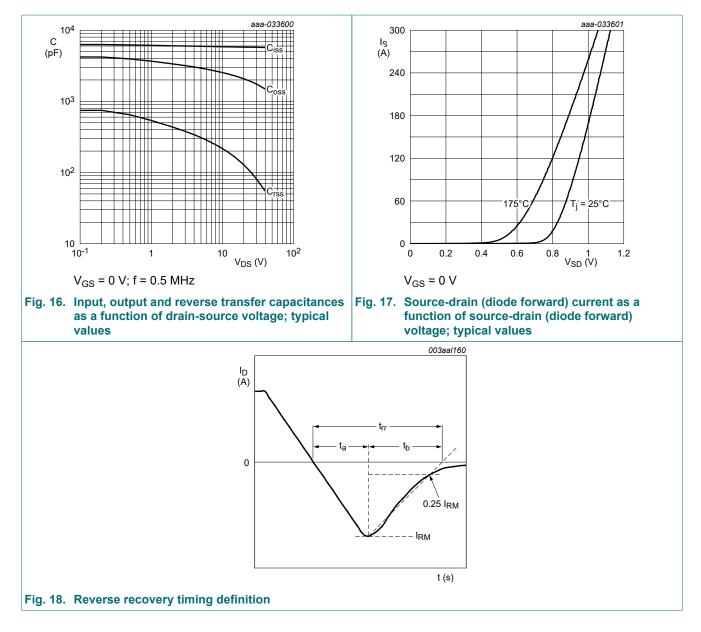
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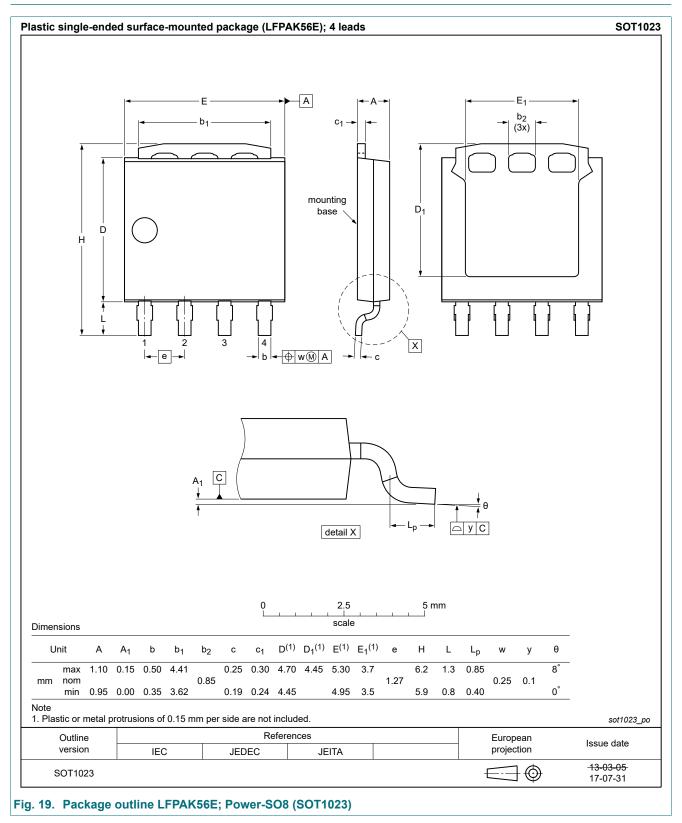
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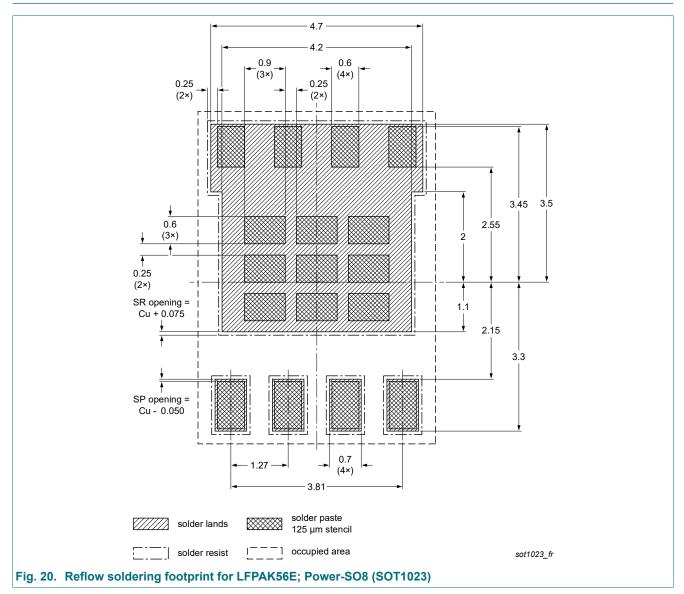
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11. Package outline



12. Soldering



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13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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